



DMP6023LFGQ

PowerDI3333-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C
001/	25mΩ @ V _{GS} = -10V	-7.7A
-60V	33mΩ @ V _{GS} = -4.5V	-6.8A

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power-management functions
- DC-DC converters

Features and Benefits

- Low RDS(ON) Ensures on State Losses Are Minimized
- Small Form Factor Thermally Efficient Package Enables Higher Density End Products

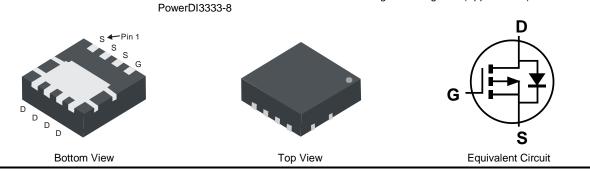
60V P-CHANNEL ENHANCEMENT MODE MOSFET

- Occupies just 33% of the Board Area Occupied by SO-8 Enabling Smaller End Product
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMP6023LFGQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Package: PowerDI[®]3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.034 grams (Approximate)



Ordering Information (Note 4)

Part Number	Baakaga	Packing			
Fart Nulliper	Package	Qty.	Carrier		
DMP6023LFGQ-7	PowerDI3333-8	2,000	Tape & Reel		
DMP6023LFGQ-13	PowerDI3333-8	3,000	Tape & Reel		

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

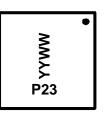
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



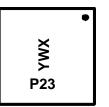
Marking Information

Site1:



P23 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)

Site2:



P23 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 3 = 2023) W = Week (ex: a = Week 27, z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Key

Year	2016	-	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	6	-	3	4	5	6	7	8	9	0	1	2
Week	1-26			27-52			53					
Code	A-Z			a-z			Z					
Internal Code	Sı	ın	Mor	ı	Tue	'	Wed	Thu		Fri		Sat
Code	Г	-	U		V		W	Х		Y		Z

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	VDSS	-60	V		
Gate-Source Voltage	Vgss	±20	V		
	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	lo	-7.7 -6.2	A
Continuous Drain Current (Note 6) V _{GS} = -10V	t < 10s	T _A = +25°C T _A = +70°C	lo	-10.3 -8.2	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	IDM	-55	A		
Maximum Continuous Body Diode Forward Current	ls	-2.2	A		
Avalanche Current, L = 0.1mH	alanche Current, L = 0.1mH			-35.5	A
Avalanche Energy, L = 0.1mH	Eas	62.9	mJ		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1.0	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	123	°C/W	
mermai Resistance, Junction to Ambient (Note 5)	t < 10s	RθJA	69		
Total Power Dissipation (Note 6)		PD	2.1	W	
Thermal Registeres, Junction to Ambient (Note 6)	Steady State	D	60		
Thermal Resistance, Junction to Ambient (Note 6)		RθJA	34	°C/W	
Thermal Resistance, Junction to Case (Note 6)		Rejc	6.3		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

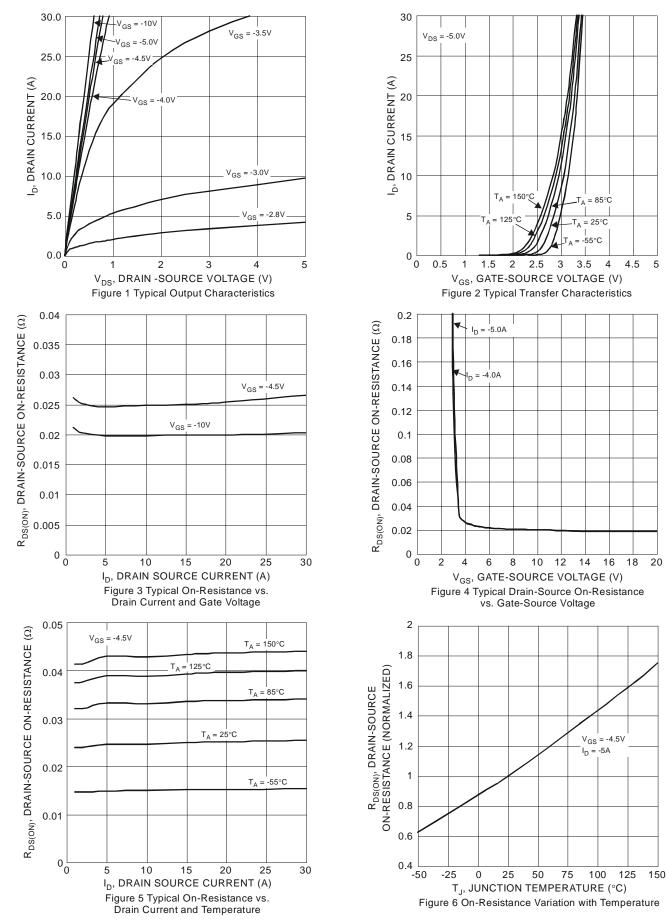
			•			
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				•		-
Drain-Source Breakdown Voltage	BV _{DSS}	-60			V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current TJ = +25°C	IDSS		—	-1	μA	$V_{DS} = -60V, V_{GS} = 0V$
Gate-Source Leakage	lgss		_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	-1	—	-3	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Bacou		11	25	mΩ	$V_{GS} = -10V, I_D = -5A$
	Rds(on)	—	13	33	11152	$V_{GS} = -4.5V, I_{D} = -4A$
Diode Forward Voltage	V _{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	2569	—	pF	
Output Capacitance	Coss	_	179	—	pF	VDS = -30V, VGS = 0V, f = 1MHz
Reverse Transfer Capacitance	Crss	—	143	—	pF	
Gate Resistance	Rg	_	8	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge (V _{GS} = -4.5V)	Qg	_	26.5	—	nC	
Total Gate Charge (V _{GS} = -10V)	Qg	_	53.1	—	nC	
Gate-Source Charge	Qgs		7.1	—	nC	$V_{DS} = -30V, I_{D} = -5A$
Gate-Drain Charge	Q _{gd}	_	12.6	—	nC	
Turn-On Delay Time	t _{D(ON)}		6	_	ns	
Turn-On Rise Time	tR	_	7.1	_	ns	Vgs = -10V, Vds = -30V,
Turn-Off Delay Time	tD(OFF)		110	—	ns	$R_g = 3\Omega$, $I_D = -5A$
Turn-Off Fall Time	tF		62	—	ns	7
Body Diode Reverse Recovery Time	trr	_	20	—	ns	
Body Diode Reverse Recovery Charge	Q _{RR}		14	_	nC	I _F = -5A, di/dt = 100A/μs

 Notes:
 7. Short duration pulse test used to minimize self-heating effect.

 8. Guaranteed by design. Not subject to product testing.

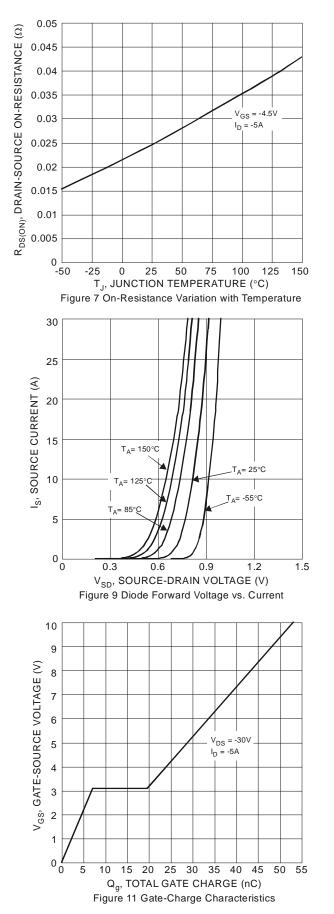


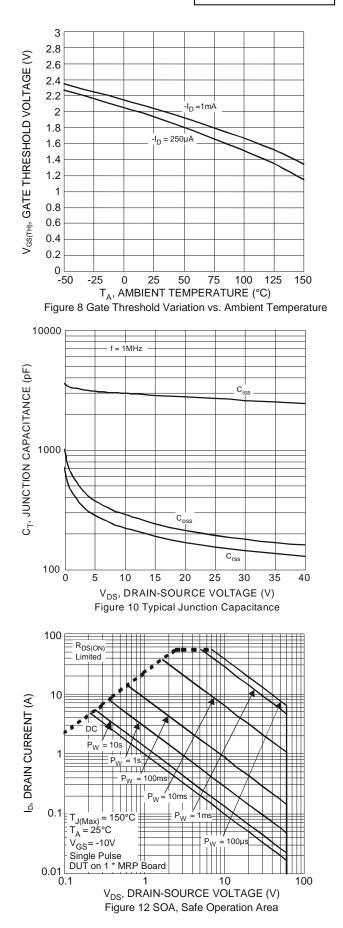
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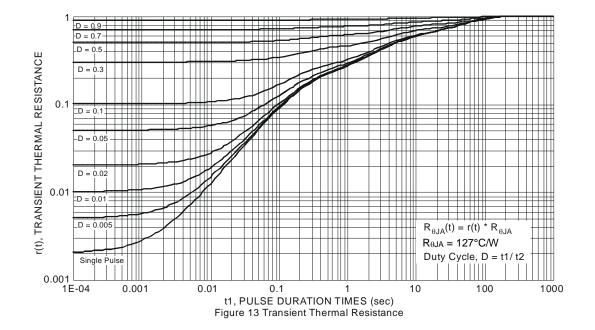
DMP6023LFGQ Document number: DS38647 Rev. 3 - 2







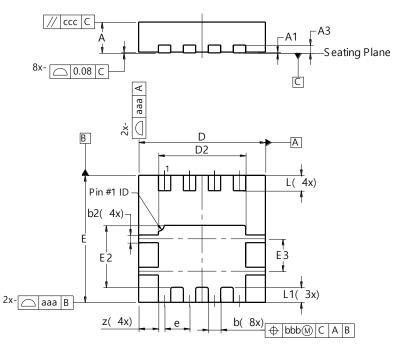






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

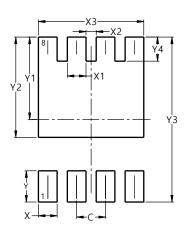


D DI000 0									
	PowerDI3333-8								
Dim	Min	Max	Тур						
Α	0.75	0.85	0.80						
A1	0.00	0.05	0.02						
A3	-	-	0.203						
b	0.27	0.37	0.32						
b2	-	-	0.20						
D	3.25	3.35	3.30						
D2	2.22 2.32		2.27						
Е	3.25	3.35	3.30						
E2	1.56	1.66	1.61						
E3	0.79	0.89	0.84						
е	-	-	0.65						
L	0.35	0.45	0.40						
L1	-	-	0.39						
z	0.515								
aaa	0.25								
bbb		0.10							
CCC		0.10							
All I	Dimens	sions ir	n mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540

PowerDI3333-8



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